

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - · Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



54125/DM54125/DM74125 Quad TRI-STATE® Buffers

General Description

This device contains four independent gates each of which performs a non-inverting buffer function. The outputs have the TRI-STATE feature. When enabled, the outputs exhibit the low impedance characteristics of a standard TTL output with additional drive capability at the high Logic level to permit the driving of bus lines without external pull-up resistors. When disabled, both the output transistors are turned off presenting a high-impedance state to the bus line. Thus the output will act neither as a significant load nor as a driver.

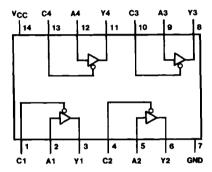
To minimize the possibility that two outputs will attempt to take a common bus to opposite logic levels, the disable time is shorter than the enable time of the outputs.

Features

 Alternate Military/Aerospace device (54125) is available. Contact a National Semiconductor Sales Office/ Distributor for specifications.

Connection Diagram

Dual-In-Line Package



TL/F/6540-1

Order Number 54125DMQB, 54125FMQB, DM54125J, DM54125W or DM74125N See NS Package Number J14A, N14A or W14B

Function Table

	Y = A	
Inputs		Output
A	С	Υ
L	L	L
н	L	Н
X	Ħ	Hi-Z

H = High Logic Level

L = Low Logic Level

X = Either Low or High Logic Level

Hi-Z = TRI-STATE (Outputs are disabled)

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V
Input Voltage 5.5V
Operating Free Air Temperature Research

Operating Free Air Temperature Range
DM54 and 54
-55

Storage Temperature Range

-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	DM54125			DM74125			Units
		Min	Nom	Max	Min	Nom	Max	
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High Level Input Voltage	2			2			V
V_{IL}	Low Level Input Voltage			0.8			0.8	V
Юн	High Level Output Current			-2			-5.2	mA
loL	Low Level Output Current			16			16	mA
TA	Free Air Operating Temperature	55		125	0		70	°C

Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_1 = -12 \text{ mA}$				-1.5	٧
V _{OH}	High Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max, V_{IH} = Min$	_	2.4	3.3		٧
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min, V_{IL} = Max$			0.2	0.4	٧
l _l	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$				1	mA
l _{IH}	High Level Input Current	$V_{CC} = Max, V_1 = 2.4V$		_		40	μΑ
l _{IL}	Low Level Input Current	$V_{CC} = Max, V_1 = 0.4V$				1.6	mA
lIZL	Off-State Input Current with Low Level Input Voltage Applied	$V_{CC} = Max, V_I = 0.4V$				-40	μА
Гохн	Off-State Output Current with High Level Output Voltage Applied	$V_{CC} = Max, V_O = 2.4V$ $V_{IH} = Min, V_{IL} = Max$				40	μΑ
lozL	Off-State Output Current with Low Level Output Voltage Applied	$V_{CC} = Max, V_O = 0.4V$ $V_{IH} = Min, V_{IL} = Max$				-40	μΑ
los	Short Circuit	V _{CC} = Max	DM54	-30		-70	mA
	Output Current	(Note 2)	DM74	-28		-70] ''''
Icc	Supply Current	V _{CC} = Max (Note 3)			36	54	mA

Note 1: All typicals are at $V_{CC} = 5V$, $T_A = 25$ °C.

Note 2: Not more than one output should be shorted at a time.

Note 3: I_{CC} is measured with the output control (C) inputs at 4.5V, the data inputs grounded, and the outputs open.

Switching Characteristics at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter					
		C _L = 5 pF		C _L = 50 pF		Units
		Min	Max	Min	Max	
t _{PLH}	Propagation Delay Time Low to High Level Output		-		15	ns
tpHL	Propagation Delay Time High to Low Level Output				18	ns
^t PZH	Output Enable Time to High Level Output		1		18	ns
t _{PZL}	Output Enable Time to Low Level Output				25	ns
t _{PHZ}	Output Disable Time from High Level Output		8			ns
t _{PLZ}	Output Disable Time from Low Level Output		14			ns